Appl. Ser. No. 09/857,673

Att. Docket No. 10191/1840

Reply to Office Action of August 1, 2003

Amendments to the CLAIMS:

Without prejudice, this listing of the claims replaces all prior versions and listings of the claims in the present application:

LISTING OF CLAIMS:

1-21. (Canceled).

22. (Currently Amended) A method of packaging electronic components, comprising the steps of:

forming a plurality of cavities in a package substrate, the package substrate being made of one of a semiconductor material and a photopatternable glass;

mounting the electronic components in the plurality of cavities;

sealing the plurality of cavities with one of a cover substrate and a cover layer; and separating the electronic components,

wherein the package substrate includes a thinned central area and a remaining thick substrate edge that stabilizes the package substrate and that is used for handling purposes.

- 23. (Previously Presented) The method according to claim 22, wherein the semiconductor material is silicon.
- 24. (Currently Amended) The method according to claim 22, wherein the package substrate includes a first side facing toward the one of the cover substrate and the cover layer and a second side facing away from the one of the cover substrate and thr the cover layer, the second side including a metal layer for contacting the electrical components.
- 25. (Previously Presented) The method according to claim 24, wherein the first side of the package substrate includes an insulation layer.
- 26. (Previously Presented) The method according to claim 22, wherein the plurality of cavities are produced by etching using photostructuring.

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- 27. (Previously Presented) The method according to claim 22, wherein the plurality of cavities are designed as passages through the package substrate.
- 28. (Previously Presented) The method according to claim 22, wherein the plurality of cavities are shallow to accommodate the electronic components.
- 29. (Previously Presented) The method according to claim 22, further comprising the steps of:

applying a number of the electronic components corresponding to a number of the plurality of cavities formed on the package substrate to a component carrier layer; and joining the package substrate to the component carrier layer.

- 30. (Previously Presented) The method according to claim 29, wherein the component carrier layer is a metal layer.
- 31. (Previously Presented) The method according to claim 30, wherein the component carrier layer is a layer of silver.
- 32. (Previously Presented) The method according to claim 22, wherein the electronic components include a diode.
- 33. (Previously Presented) The method according to claim 32, wherein the diode is a Gunn diode.
- 34. (Previously Presented) The method according to claim 22, wherein the one of the cover substrate and the cover layer is made of the semiconductor material and is used to contact a terminal of the electronic components.
- 35. (Previously Presented) The method according to claim 34, wherein the semiconductor material is silicon.

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- 36. (Previously Presented) The method according to claim 29, further comprising the step of: applying contact springs to the one of the cover substrate and the cover layer for contacting the electronic components.
- 37. (Previously Presented) The method according to claim 36, wherein the contact springs are produced by a galvanic metal deposition.
- 38. (Previously Presented) The method according to claim 22, wherein the one of the cover substrate and the cover layer is made of an organic dielectric.
- 39. (Previously Presented) The method according to claim 38, further comprising the step of: applying a contact for establishing an electric connection to a terminal of a respective one of the electronic components by:
 - i) etching contact holes through the organic dielectric, and
 - ii) applying a metal layer,

wherein the organic dielectric is a photosensitive lacquer.

- 40. (Previously Presented) The method according to claim 22, wherein the electronic components are separated by sawing.
- 41. (Previously Presented) The method according to claim 22, further comprising the steps of: arranging the package substrate as an insulating carrier layer; enclosing the plurality of cavities by insulator structures situated outside the package substrate;

applying the electronic components to a component carrier layer; and mounting the electronic components in the plurality of cavities by joining the component carrier layer, the insulator structures, and the one of the cover substrate and the cover layer.

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42. (Previously Presented) The method according to claim 41, further comprising the steps of:

joining the one of the cover substrate and the cover layer and the package substrate; forming separate insulator structures; and joining the component carrier layer to the electronic components.

43. (Previously Presented) The method according to claim 41, further comprising the steps of:

joining the component carrier layer and the package substrate; forming separate insulator structures; and joining the one of the cover substrate and the cover layer to the package substrate.

- 44. (Previously Presented) The method according to claim 41, wherein the package substrate is arranged as a carrier layer, made of a photopatternable glass, wherein the insulation structures are separate from each other, and wherein the separate insulator structures are exposed by a selective etching of the photopatternable glass.
- 45. (Previously Presented) The method according to claim 44, wherein the one of the cover substrate and the cover layer includes contact springs for contacting electric terminals of the electronic components.
- 46. (Previously Presented) The method according to claim 45, wherein the contact springs are produced by a galvanic deposition of metal.